

SANYO Semiconductors DATA SHEET

2SC5375A — VHF to UHF Band OSC, High-Frequency Amplifier Applications

Features

• High gain : $|S21e|^2=10dB$ typ (f=1GHz).

• High cut-off frequency: fT=5.2GHz typ.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		20	V
Collector-to-Emitter Voltage	VCEO		10	V
Emitter-to-Base Voltage	VEBO		2	V
Collector Current	IC		100	mA
Collector Dissipation	PC		150	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

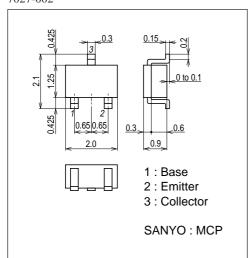
Parameter	Symbol	Conditions		Ratings			
Farameter	Symbol	Conditions	min	typ	max	Unit	
Collector Cutoff Current	ICBO	V _{CB} =10V, I _E =0A			1.0	μΑ	
Emitter Cutoff Current	IEBO	VEB=1V, IC=0A			10	μΑ	
DC Current Gain	hFE1	V _{CE} =3V, I _C =7mA	110		180		
DC Current Gain	hFE2	V _{CE} =3V, I _C =30mA	100				
Gain-Bandwidth Product	fT	VCE=3V, IC=7mA	3	5.2		GHz	
Output Capacitance	Cob	V _{CB} =3V, f=1MHz		1.0	1.5	pF	
Reverse Transfer Capacitance	Cre	V _{CB} =3V, f=1MHz		0.7		pF	
Forward Transfer Gain	S21e ²	VCE=3V, IC=7mA, f=1GHz	8	10		dB	
Noise Figure	NF	VCE=3V, IC=7mA, f=1GHz		1.4	2.5	dB	

Marking: NA

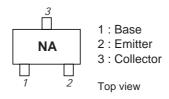
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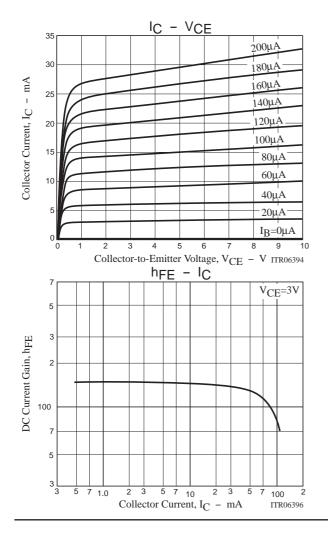
Package Dimensions

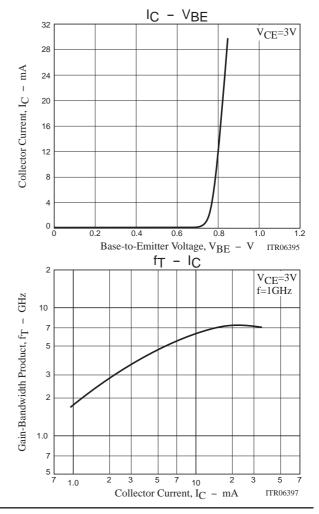
unit : mm (typ) 7027-002



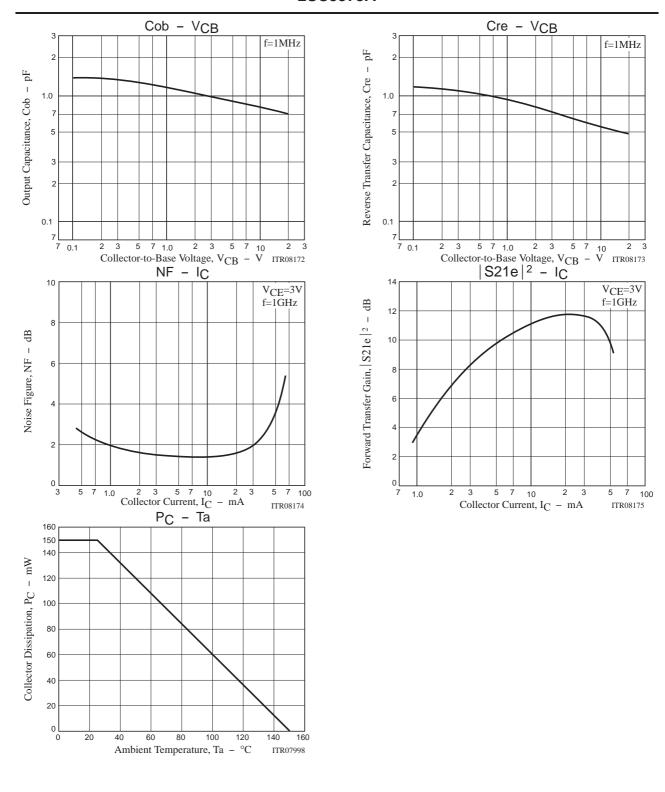
Marking







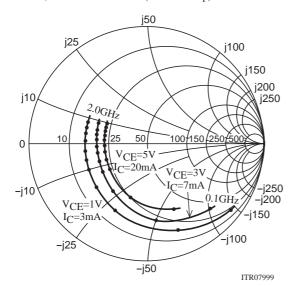
2SC5375A



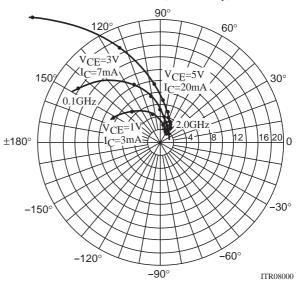
S Parameter

S11e

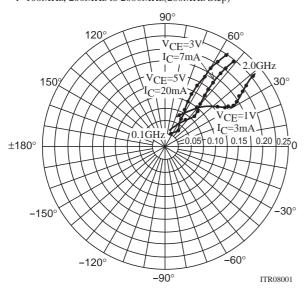
f=100MHz, 200MHz to 2000MHz(200MHz Step)



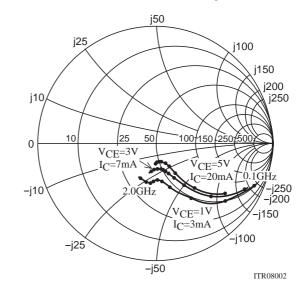
S21e f=100MHz, 200MHz to 2000MHz(200MHz Step)



S12e f=100MHz, 200MHz to 2000MHz(200MHz Step)



S22e f=100MHz, 200MHz to 2000MHz(200MHz Step)



2SC5375A

S Parameters (Common emitter)

 $V_{CE}=1V$, $I_{C}=3mA$, $Z_{O}=50\Omega$

Freq(MHz)	S ₁₁	∠S ₁₁	S ₂₁	∠S ₂₁	S ₁₂	∠S ₁₂	S ₂₂	∠S ₂₂
100	0.875	-40.1	8.529	152.1	0.062	67.4	0.905	-24.3
200	0.782	-70.7	6.673	131.8	0.101	51.6	0.745	-42.0
400	0.621	-115.9	4.733	104.7	0.135	37.2	0.524	-59.1
600	0.576	-138.2	3.353	90.2	0.143	33.3	0.387	-71.5
800	0.547	-155.7	2.686	79.1	0.151	33.0	0.329	-79.4
1000	0.542	-165.4	2.165	70.4	0.165	31.2	0.330	-80.5
1200	0.534	-174.7	1.873	62.4	0.173	33.0	0.310	-86.0
1400	0.529	178.3	1.638	55.7	0.184	35.1	0.295	-91.9
1600	0.529	170.8	1.480	49.7	0.194	35.6	0.308	-95.7
1800	0.533	165.4	1.321	43.4	0.208	36.8	0.312	-101.6
2000	0.532	159.3	1.215	38.3	0.227	38.6	0.304	-109.1

 $V_{CE}=3V$, $I_{C}=7mA$, $Z_{O}=50\Omega$

*CE 5 1, 2C 711								
Freq(MHz)	S ₁₁	$\angle S_{11}$	S ₂₁	∠S ₂₁	S ₁₂	∠S ₁₂	S ₂₂	∠S ₂₂
100	0.777	-48.9	16.116	146.5	0.040	65.9	0.852	-29.0
200	0.643	-84.8	12.223	124.2	0.061	52.9	0.646	-46.3
400	0.505	-126.1	7.484	101.5	0.083	46.6	0.428	-58.8
600	0.473	-146.2	5.198	89.7	0.096	48.3	0.317	-65.6
800	0.454	-160.6	3.984	80.7	0.112	49.9	0.273	-70.2
1000	0.446	-170.4	3.275	73.6	0.129	51.4	0.248	-74.1
1200	0.449	-177.6	2.738	66.9	0.147	52.0	0.239	-76.3
1400	0.445	175.5	2.391	61.2	0.165	52.4	0.229	-79.6
1600	0.443	168.9	2.135	55.9	0.184	52.4	0.225	-84.6
1800	0.439	164.1	1.944	50.5	0.203	51.5	0.227	-90.0
2000	0.443	157.7	1.760	45.7	0.222	50.4	0.240	-93.0

 $V_{\mbox{\footnotesize{CE}}}\!\!=\!\!5\mbox{\footnotesize{V}},\mbox{\footnotesize{Ic}}\!\!=\!\!20\mbox{\footnotesize{mA}},\mbox{\footnotesize{Z}}_{\mbox{\footnotesize{O}}}\!\!=\!\!50\Omega$

Freq(MHz)	S ₁₁	∠S ₁₁	S ₂₁	∠S ₂₁	S ₁₂	∠S ₁₂	S ₂₂	∠S ₂₂
100	0.595	-70.3	26.610	134.3	0.028	62.1	0.724	-39.3
200	0.480	-107.7	17.090	113.5	0.041	56.3	0.482	-54.3
400	0.406	-143.8	9.432	95.7	0.060	58.8	0.296	-61.9
600	0.393	-160.3	6.459	86.2	0.079	61.8	0.227	-64.4
800	0.388	-171.0	4.909	79.0	0.100	62.8	0.200	-67.5
1000	0.387	-178.6	3.989	73.3	0.121	62.8	0.188	-70.3
1200	0.390	175.1	3.356	67.3	0.142	62.0	0.182	-72.4
1400	0.385	169.8	2.918	62.1	0.163	61.0	0.176	-75.0
1600	0.386	163.9	2.588	57.7	0.184	59.9	0.173	-80.1
1800	0.388	159.8	2.322	52.8	0.205	57.9	0.177	-85.8
2000	0.394	154.7	2.117	48.5	0.226	56.0	0.185	-89.4

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